



# STTA506D/F/B

## TURBOSWITCH™ ULTRA-FAST HIGH VOLTAGE DIODE

### MAIN PRODUCTS CHARACTERISTICS

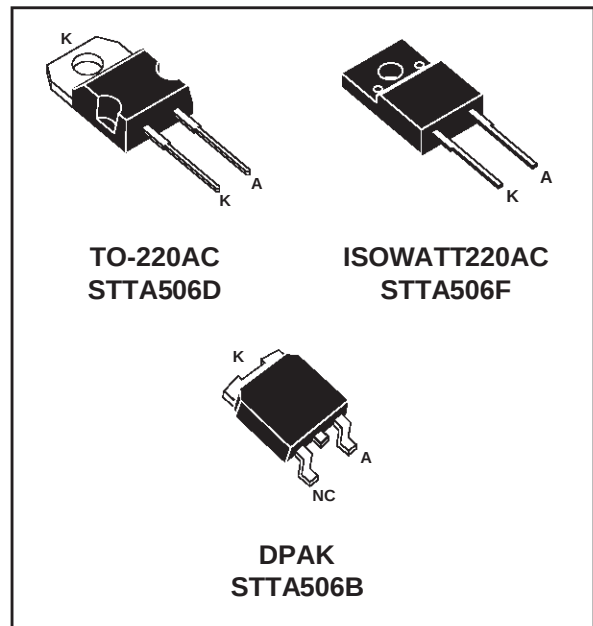
|                |      |
|----------------|------|
| $I_F(AV)$      | 5A   |
| $V_{RRM}$      | 600V |
| $t_{rr} (typ)$ | 20ns |
| $V_F (max)$    | 1.5V |

### FEATURES AND BENEFITS

- SPECIFIC TO "FREEWHEEL MODE" OPERATIONS: FREEWHEEL OR BOOSTER DIODE
- ULTRA-FAST AND SOFT RECOVERY
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR
- HIGH FREQUENCY OPERATIONS
- INSULATED PACKAGE: ISOWATT220AC  
Electrical insulation : 2000VDC  
Capacitance < 12 pF

### DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V. TURBOSWITCH family, drastically cuts losses in both the diode and the associated switching IGBT or MOSFET in all "freewheel mode" operations



and is particularly suitable and efficient in motor control freewheel applications and in booster diode applications in power factor control circuitries. Packaged either in TO-220AC, ISOWATT220AC or in DPAK, these 600V devices are particularly intended for use on 240V domestic mains.

### ABSOLUTE RATINGS (limiting values)

| Symbol       | Parameter                              |                              | Value      | Unit |
|--------------|----------------------------------------|------------------------------|------------|------|
| $V_{RRM}$    | Repetitive peak reverse voltage        |                              | 600        | V    |
| $V_{RSM}$    | Non repetitive peak reverse voltage    |                              | 600        | V    |
| $I_{F(RMS)}$ | RMS forward current                    | TO-220AC                     | 20         | A    |
|              |                                        | ISOWATT220AC                 |            |      |
|              |                                        | DPAK                         | 10         | A    |
| $I_{FRM}$    | Repetitive peak forward current        | $t_p=5\mu s$ $F=5kHz$ square | 65         | A    |
| $I_{FSM}$    | Surge non repetitive forward current   | $t_p=10 ms$ sinusoidal       | 55         | A    |
| $T_j$        | Maximum operating junction temperature |                              | 150        | °C   |
| $T_{stg}$    | Storage temperature range              |                              | -65 to 150 | °C   |

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**STTA506D/F/B****THERMAL AND POWER DATA**

| Symbol        | Parameter                                                             | Test conditions                |                                           | Value      | Unit |
|---------------|-----------------------------------------------------------------------|--------------------------------|-------------------------------------------|------------|------|
| $R_{th(j-c)}$ | Junction to case                                                      | TO-220AC/ DPAK<br>ISOWATT220AC |                                           | 3.5<br>6.0 | °C/W |
| $P_1$         | Conduction power dissipation •<br>$I_{F(AV)} = 5A$ $\delta = 0.5$     | TO-220AC/ DPAK<br>ISOWATT220AC | $T_c = 118^\circ C$<br>$T_c = 96^\circ C$ | 9          | W    |
| $P_{max}$     | Total power dissipation<br>$P_{max} = P_1 + P_3$ ( $P_3 = 10\% P_1$ ) | TO-220AC/ DPAK<br>ISOWATT220AC | $T_c = 115^\circ C$<br>$T_c = 90^\circ C$ | 10         | W    |

**STATIC ELECTRICAL CHARACTERISTICS**

| Symbol     | Parameter               | Test conditions            |                                           | Min | Typ  | Max         | Unit          |
|------------|-------------------------|----------------------------|-------------------------------------------|-----|------|-------------|---------------|
| $V_F^*$    | Forward voltage drop    | $I_F = 5A$                 | $T_j = 25^\circ C$<br>$T_j = 125^\circ C$ |     |      | 1.75<br>1.5 | V<br>V        |
| $I_R^{**}$ | Reverse leakage current | $V_R = 0.8 \times V_{RRM}$ | $T_j = 25^\circ C$<br>$T_j = 125^\circ C$ |     | 0.75 | 100<br>2    | $\mu A$<br>mA |
| $V_{to}$   | Threshold voltage       | $I_p < 3 \cdot I_{AV}$     | $T_j = 125^\circ C$                       |     |      | 1.15        | V             |
| $r_d$      | Dynamic resistance      |                            |                                           |     |      | 70          | m $\Omega$    |

Test pulse : \*  $t_p = 380 \mu s$ ,  $\delta < 2\%$ \*\*  $t_p = 5 ms$ ,  $\delta < 2\%$ 

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_{F(AV)} + r_d \times I_F^2 (RMS)$$

**DYNAMIC ELECTRICAL CHARACTERISTICS****TURN-OFF SWITCHING**

| Symbol   | Parameter                        | Test conditions                                                                                                   | Min | Typ  | Max | Unit |
|----------|----------------------------------|-------------------------------------------------------------------------------------------------------------------|-----|------|-----|------|
| $t_{rr}$ | Reverse recovery time            | $T_j = 25^\circ C$<br>$I_F = 0.5 A$ $I_R = 1A$ $I_{rr} = 0.25A$<br>$I_F = 1 A$ $di_F/dt = -50A/\mu s$ $V_R = 30V$ |     | 20   | 50  | ns   |
| $I_{RM}$ | Maximum reverse recovery current | $T_j = 125^\circ C$ $V_R = 400V$ $I_F = 5A$<br>$di_F/dt = -40 A/\mu s$<br>$di_F/dt = -500 A/\mu s$                |     | 11   | 3.0 | A    |
| S factor | Softness factor                  | $T_j = 125^\circ C$ $V_R = 400V$ $I_F = 5A$<br>$di_F/dt = -500 A/\mu s$                                           |     | 0.55 |     | -    |

**TURN-ON SWITCHING**

| Symbol   | Parameter             | Test conditions                                                                                 | Min | Typ | Max | Unit |
|----------|-----------------------|-------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| $t_{fr}$ | Forward recovery time | $T_j = 25^\circ C$<br>$I_F = 5 A$ , $di_F/dt = 40 A/\mu s$<br>measured at $1.1 \times V_{Fmax}$ |     |     | 500 | ns   |
| $V_{Fp}$ | Peak forward voltage  | $T_j = 25^\circ C$<br>$I_F = 5A$ , $di_F/dt = 40 A/\mu s$                                       |     |     | 10  | V    |

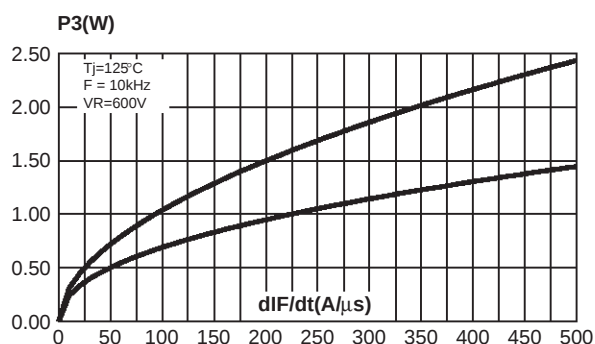
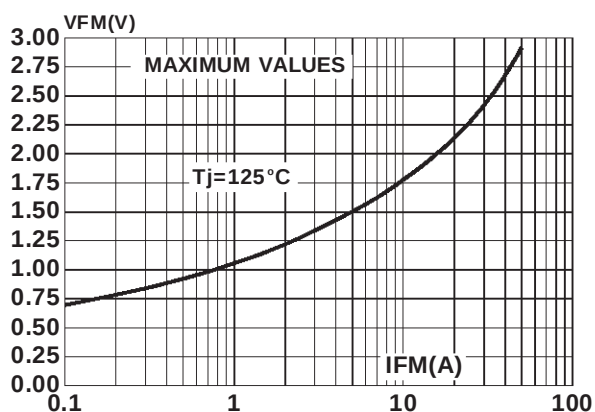
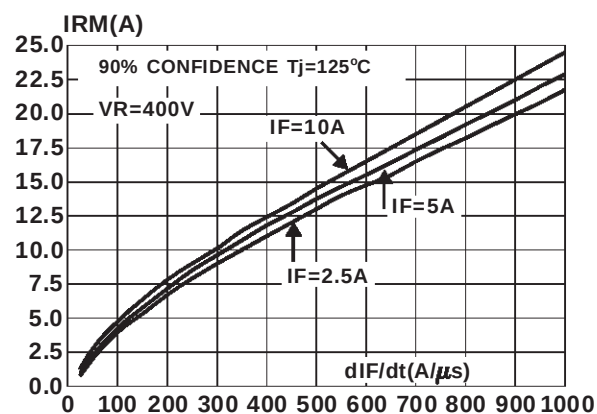
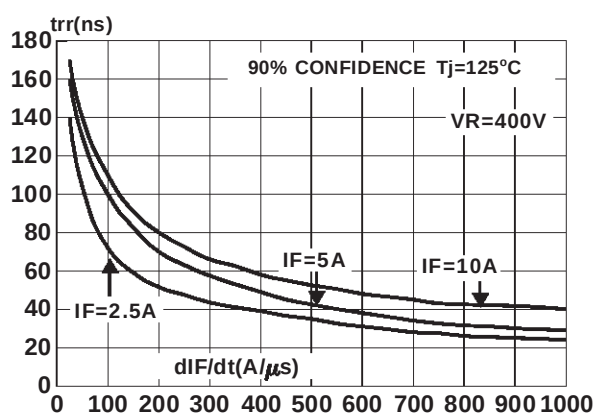
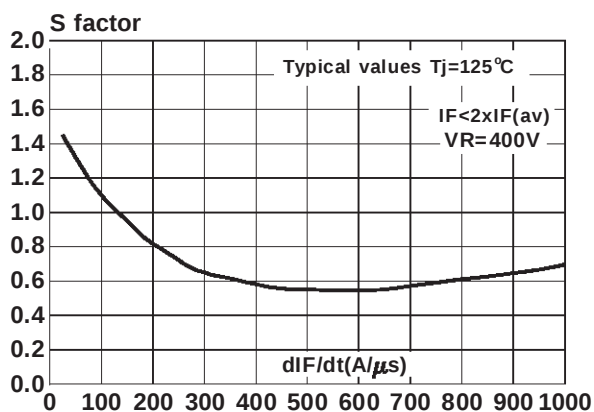
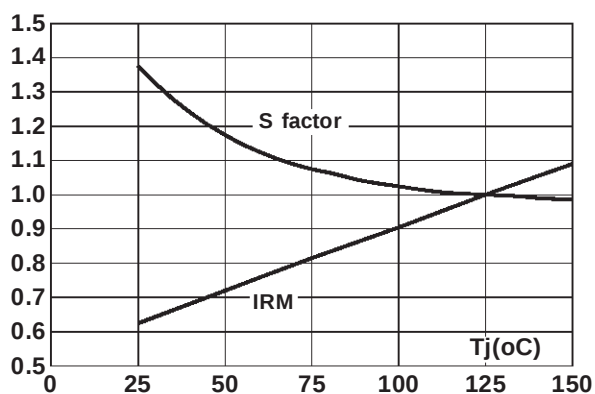
**Fig. 1:** Switching OFF losses versus  $di/dt$ .**Fig. 2:** Forward voltage drop versus forward current.**Fig. 3:** Peak reverse recovery current versus  $di_F/dt$ .**Fig. 4:** Reverse recovery time versus  $di_F/dt$ .**Fig. 5:** Softness factor ( $t_b/t_a$ ) versus  $di_F/dt$ .**Fig. 6:** Relative variation of dynamic parameters versus junction temperature (reference  $T_j = 125^\circ\text{C}$ ).

Fig. 7: Transient peak forward voltage versus  $di_F/dt$ .

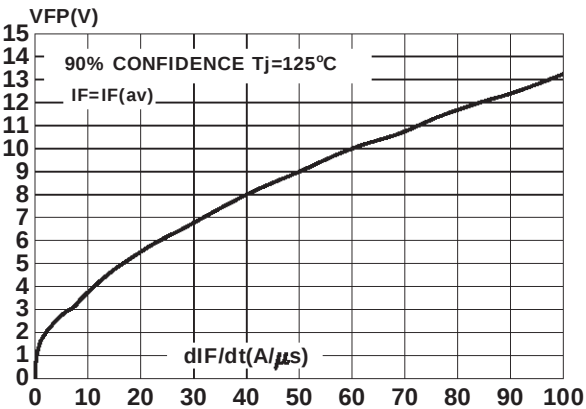


Fig. 8: Forward recovery time versus  $di_F/dt$ .

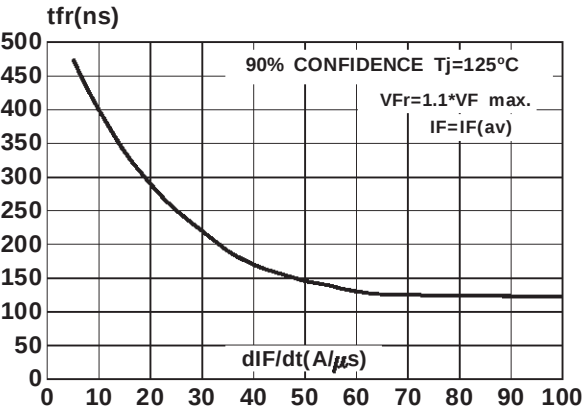


Fig. 9: Relative variation of thermal transient impedance junction to case versus pulse duration (TO-220AC and DPAK).

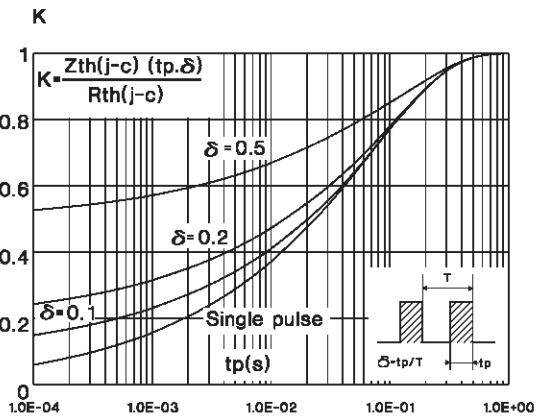
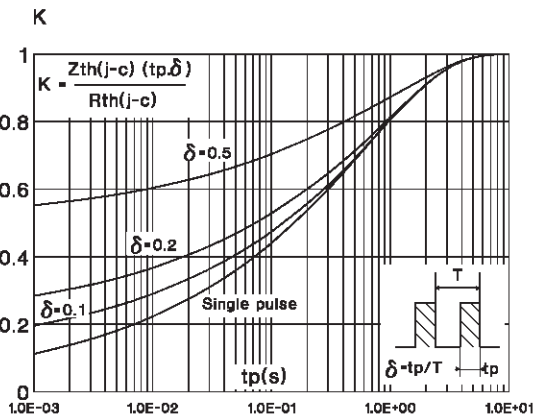


Fig. 10: Relative variation of thermal transient impedance junction to case versus pulse duration (ISOWATT220AC).



## APPLICATION DATA

The TURBOSWITCH is especially designed to provide the lowest overall power losses in any "FREEWHEEL Mode" application (Fig.A) considering both the diode and the companion transistor, thus optimizing the overall performance in the end application.

The way of calculating the power losses is given below:

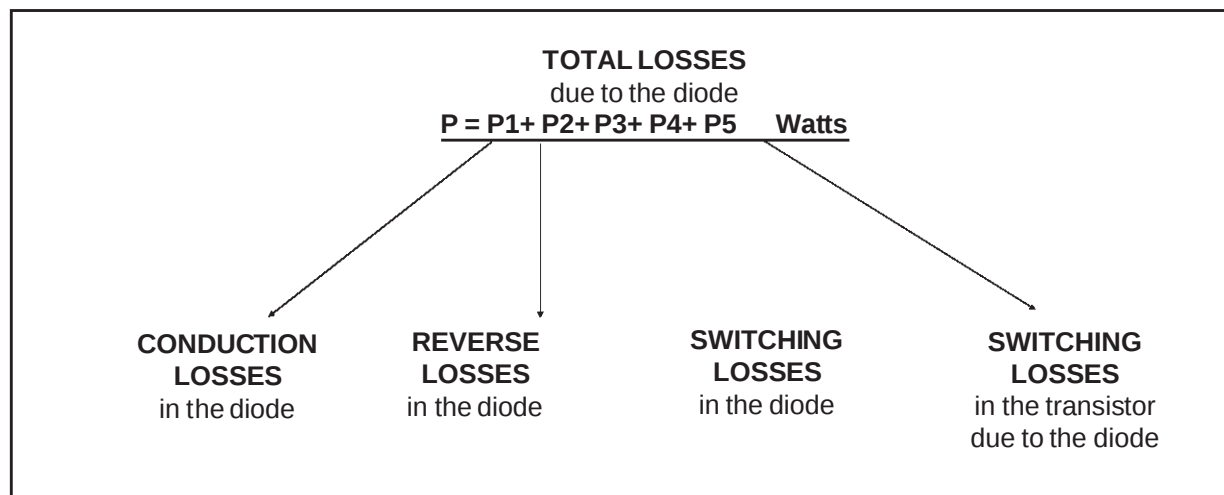
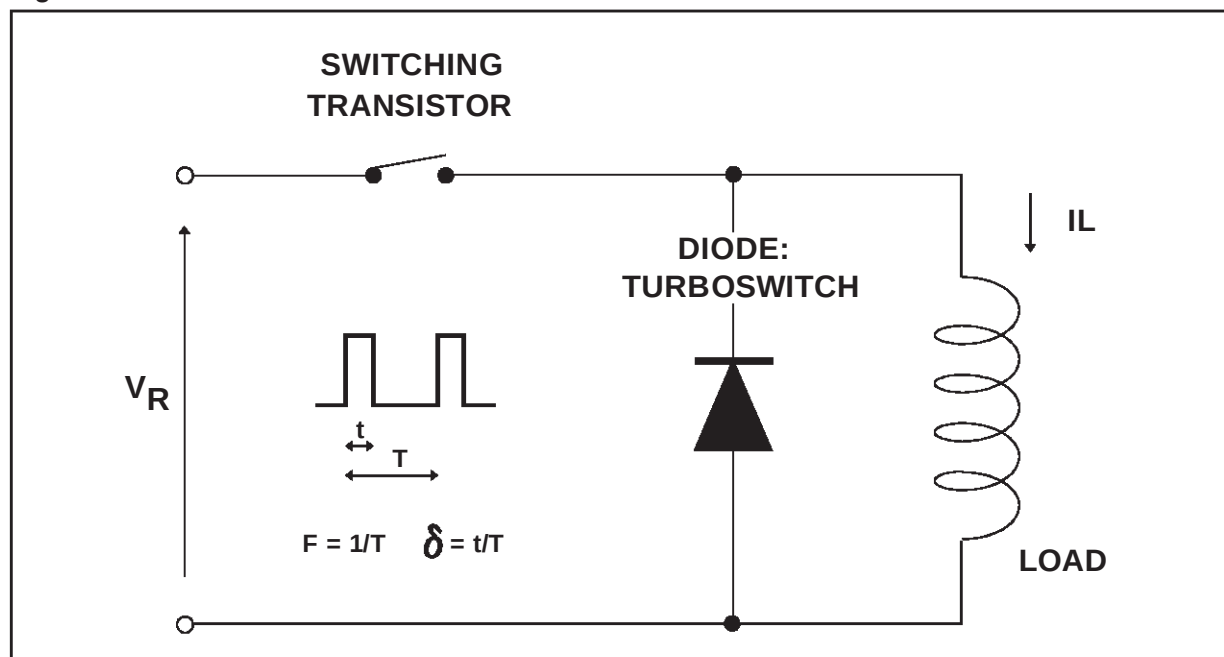
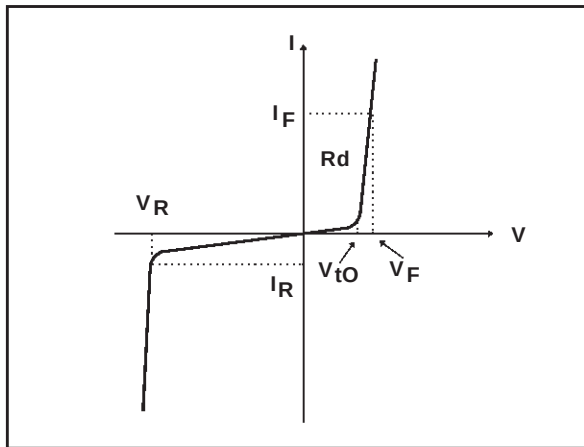


Fig. A : "FREEWHEEL" MODE



APPLICATION DATA (Cont'd)

Fig. B : STATIC CHARACTERISTICS



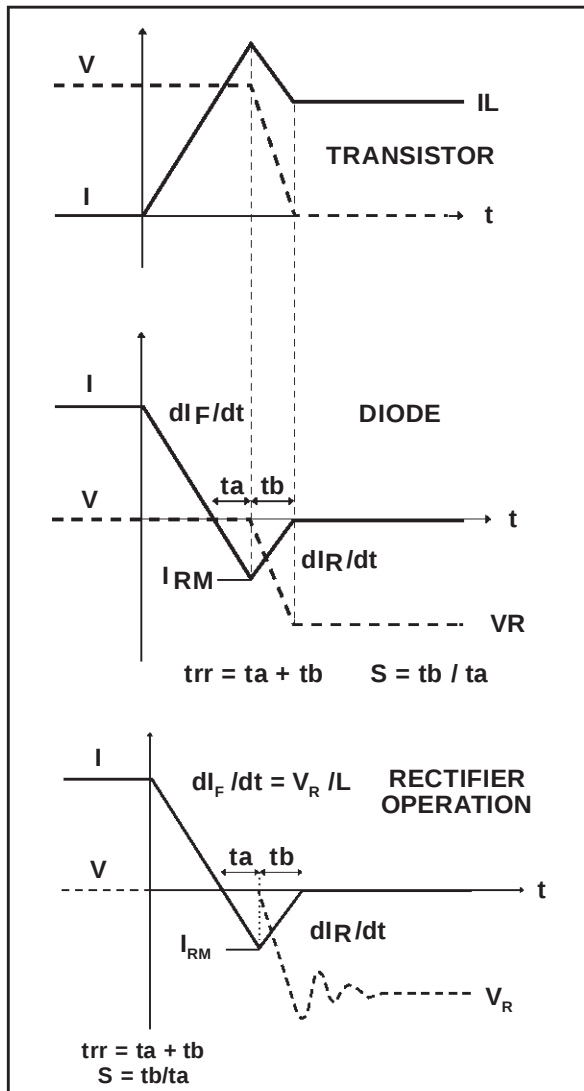
**Conduction losses :**

$$P1 = V_{t0} \cdot I_F(AV) + R_d \cdot I_F^2(RMS)$$

**Reverse losses :**

$$P2 = V_R \cdot I_R \cdot (1 - \delta)$$

Fig. C : TURN-OFF CHARACTERISTICS



**Turn-on losses :**  
(in the transistor, due to the diode)

$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI_F/dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dI_F/dt}$$

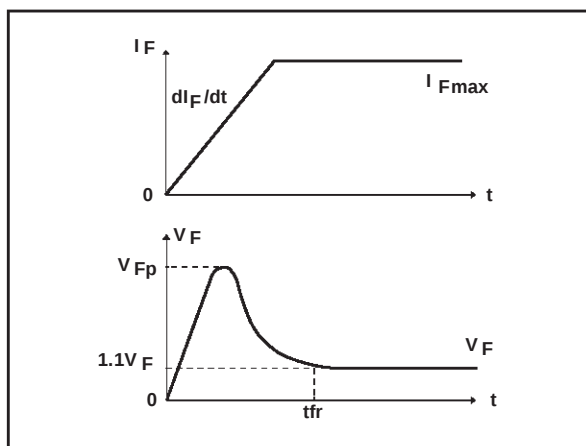
**Turn-off losses (in the diode) :**

$$P3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt}$$

P3 and P5 are suitable for power MOSFET and IGBT

## APPLICATION DATA (Cont'd)

Fig. D : TURN-ON CHARACTERISTICS

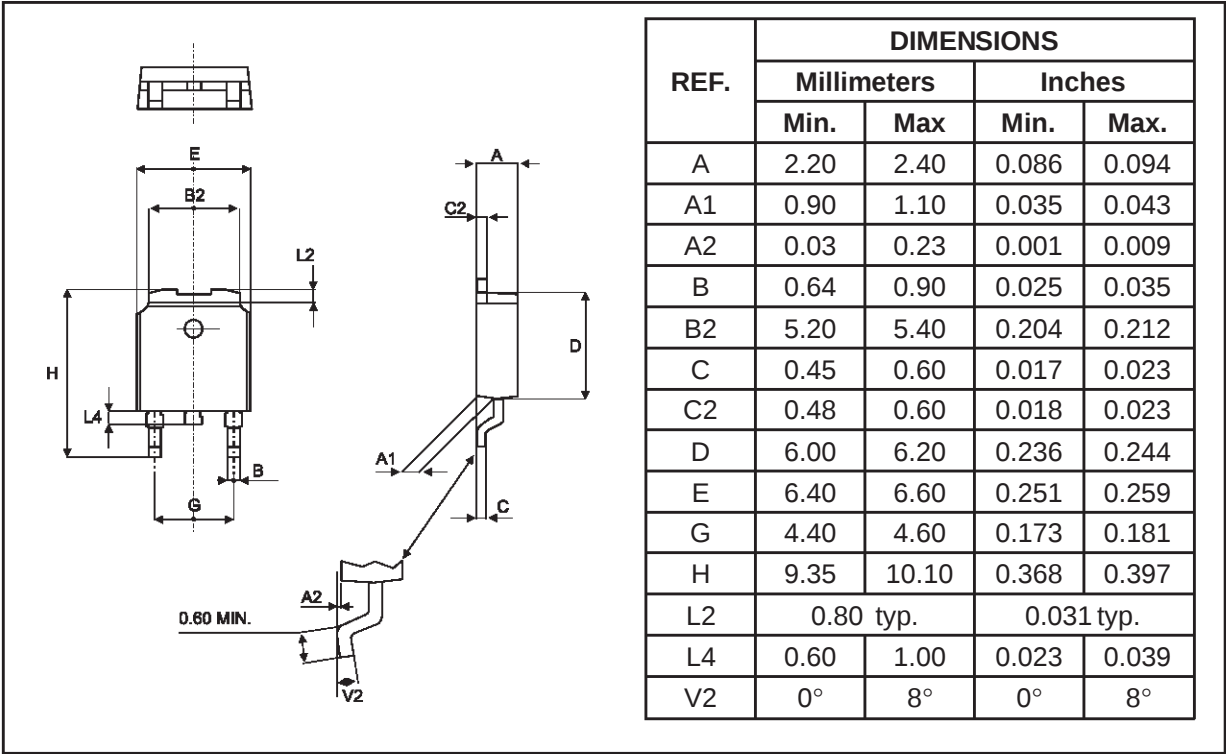


**Turn-on losses :**

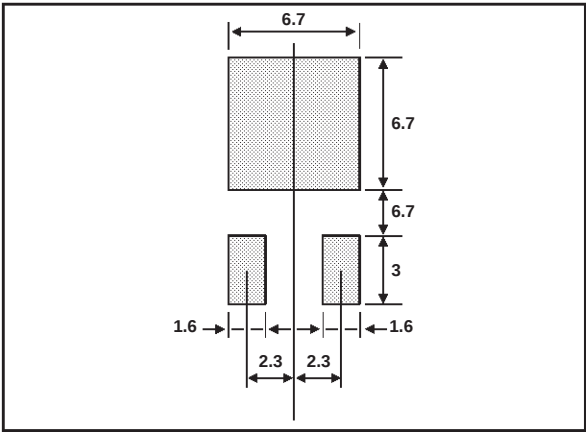
$$P_4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot t_{fr} \cdot F$$

STTA506D/F/B

PACKAGE MECHANICAL DATA  
DPAK

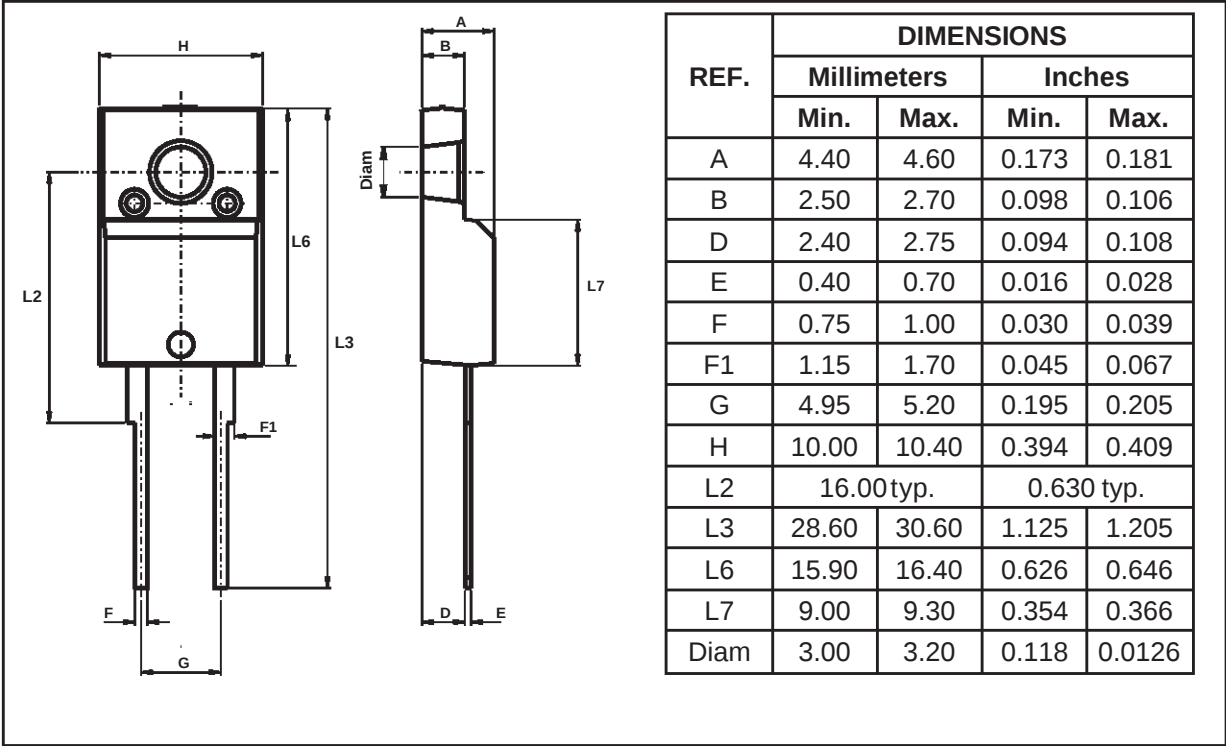


FOOTPRINT DIMENSIONS (in millimeters)



■ Cooling method : by conduction (C)

PACKAGE MECHANICAL DATA  
ISOWATT220AC



- Cooling method : by conduction (C)
- Recommended torque value : 0.55m.N
- Maximum torque value : 0.7m.N

## STTA506D/F/B

### PACKAGE MECHANICAL DATA TO-220AC

| REF.    | DIMENSIONS  |       |            |       |
|---------|-------------|-------|------------|-------|
|         | Millimeters |       | Inches     |       |
|         | Min.        | Max.  | Min.       | Max.  |
| A       | 4.40        | 4.60  | 0.173      | 0.181 |
| C       | 1.23        | 1.32  | 0.048      | 0.051 |
| D       | 2.40        | 2.72  | 0.094      | 0.107 |
| E       | 0.49        | 0.70  | 0.019      | 0.027 |
| F       | 0.61        | 0.88  | 0.024      | 0.034 |
| F1      | 1.14        | 1.70  | 0.044      | 0.066 |
| G       | 4.95        | 5.15  | 0.194      | 0.202 |
| H2      | 10.00       | 10.40 | 0.393      | 0.409 |
| L2      | 16.40 typ.  |       | 0.645 typ. |       |
| L4      | 13.00       | 14.00 | 0.511      | 0.551 |
| L5      | 2.65        | 2.95  | 0.104      | 0.116 |
| L6      | 15.25       | 15.75 | 0.600      | 0.620 |
| L7      | 6.20        | 6.60  | 0.244      | 0.259 |
| L9      | 3.50        | 3.93  | 0.137      | 0.154 |
| M       | 2.6 typ.    |       | 0.102 typ. |       |
| Diam. I | 3.75        | 3.85  | 0.147      | 0.151 |

- Cooling method : by conduction (C)
- Recommended torque value : 0.55m.N
- Maximum torque value : 0.7m.N

| Ordering type | Marking  | Package      | Weight | Base qty | Delivery mode |
|---------------|----------|--------------|--------|----------|---------------|
| STTA506D      | STTA506D | TO-220AC     | 1.86g  | 50       | Tube          |
| STTA506F      | STTA506F | ISOWATT220AC | 2g     | 50       | Tube          |
| STTA506B      | STTA506B | DPAK         | 0.3g   | 75       | Tube          |
| STTA506B-TR   | STTA506B | DPAK         | 0.3g   | 2500     | Tape & reel   |

- Epoxy meets UL94,V0

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